## Supporting information

## Enhanced thermoelectric properties of Cu<sub>1.8</sub>S via introducing ZnS nanostructures

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Figure S1 (a) Lattice parameters, (b) the cell volume of pellet samples and (c) crystallite size and micro strain plotted with respect to ZnS (x %) contents, respectively



Figure S2 Optical absorption spectra of  $Cu_{1.8}S+x$  wt.% ZnS (x = 0, 5, 10 and 20) samples



Figure S3 (a) specific heat capacity (C<sub>p</sub>), (b) diffusivity (D), (c) and Lorentz number, (d) electronic thermal conductivity ( $\kappa_e$ ), (e) lattice thermal conductivity ( $\kappa_l$ ) of Cu<sub>1.8</sub>S+ x wt.% ZnS (x = 0, 5, 10 and 20) as a function of temperature



Figure S4 Repeatability graph of temperature-dependent (a) PF and (b) zT for  $Cu_{1.8}S+5\%$  ZnS composited sample (trial-2) in comparison with early result (trial-1) in the range of 323-573 K and cooling temperature dependent zT.